

LOW VOLTAGE DETECTOR R3111xxx1A/C Series

OUTLINE

The R3111 Series are voltage detector ICs with high detector threshold accuracy and ultra-low supply current by CMOS process, which can be operated at an extremely low voltage and is used for system reset as an example.

Each of these ICs consists of a voltage reference unit, a comparator, resistors for detector threshold setting, an output driver and a hysteresis circuit. The detector threshold is fixed with high accuracy internally and does not require any adjustment. Two output types, Nch open drain type and CMOS type are available.

The R3111 Series are operable at a lower voltage than that for the RX5VL Series, and can be driven by a single battery.

Four types of packages, TO-92, SOT-89, SOT-23-5 and SC-82AB are available.

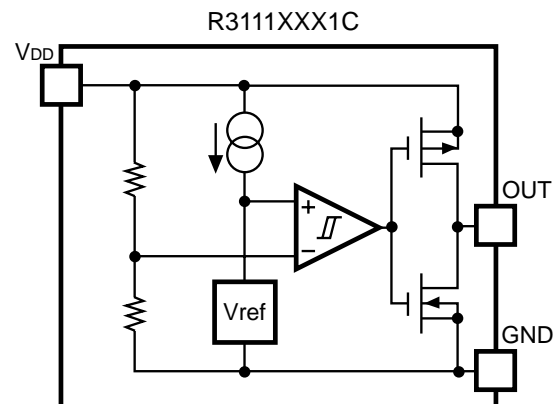
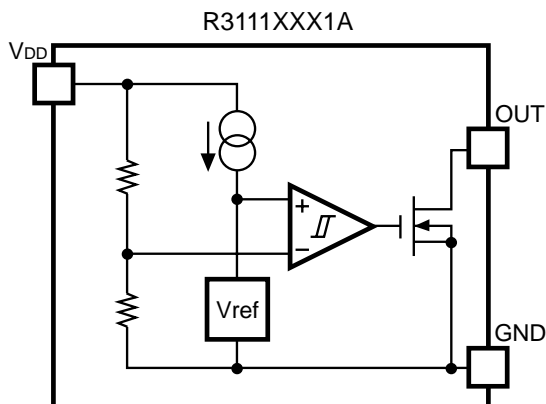
FEATURES

- Ultra-low Supply Current..... TYP. 0.8 μ A ($V_{DD}=1.5V$)
- Wide Range of Operating Voltage..... 0.7 to 10.0V($T_{opt}=25^{\circ}C$)
- Detector Threshold..... Stepwise setting with a step of 0.1V in the range of 0.9V to 6.0V is possible.
- High Accuracy Detector Threshold..... $\pm 2.0\%$
- Low Temperature-Drift Coefficient of Detector Threshold..... TYP. $\pm 100ppm/^{\circ}C$
- Two Output Types Nch Open Drain and CMOS
- Four Types of Packages..... TO-92, SOT-89(Mini-power Mold), SOT-23-5 (Mini-mold), SC-82AB

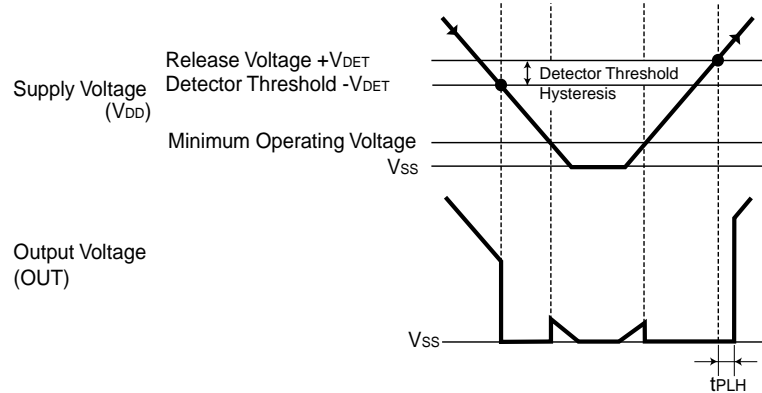
APPLICATIONS

- CPU and Logic Circuit Reset
- Battery Checker
- Window Comparator
- Wave Shaping Circuit
- Battery Back-up Circuit
- Power Failure Detector

BLOCK DIAGRAMS



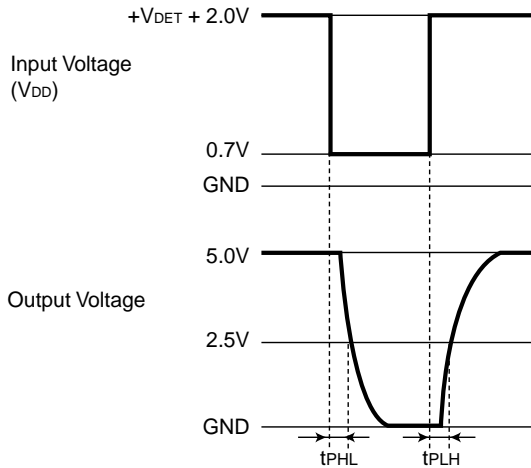
TIMING CHART



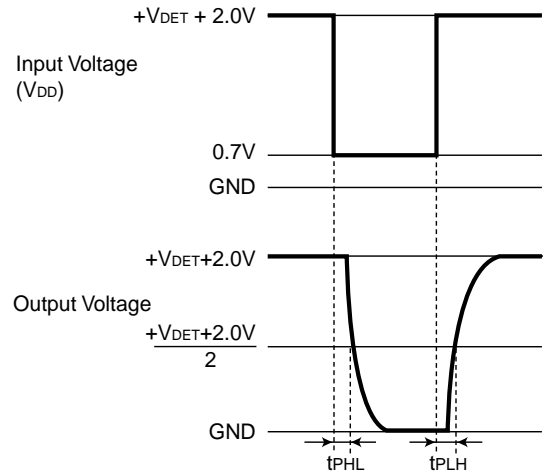
DEFINITION OF OUTPUT DELAY TIME

Output Delay Time t_{PLH} is defined as follows:

- In the case of Nch Open Drain Output:
Under the condition of the output pin (OUT) is pulled up through a resistor of 470kΩ to 5V, the time interval between the rising edge of V_{DD} pulse from 0.7V to $(+V_{DET}) + 2.0V$ and becoming of the output voltage to 2.5V.
- In the case of CMOS Output:
The time interval between the rising edge of V_{DD} pulse from 0.7V to $(+V_{DET}) + 2.0V$ and becoming of the output voltage to $(V_{DD}/2)$ V.



Nch Open Drain Output



CMOS Output

SELECTION GUIDE

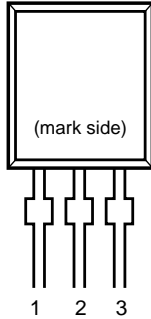
The package type, the detector threshold, the output type and the taping type of R3111 Series can be designated at the users' request by specifying the part number as follows;

R3111×××1×-×× ←Part Number
 ↑↑ ↑↑
 a b c d

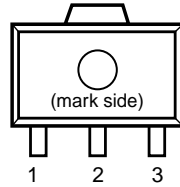
Code	Contents
a	Designation of Package Type; E: TO-92 Q: SC-82AB H: SOT-89 N: SOT-23-5
b	Setting Detector Threshold ($-V_{DET}$); Stepwise setting with a step of 0.1V in the range of 0.9V to 6.0V is possible.
c	Designation of Output Type; A: Nch Open Drain C: CMOS
d	Designation of Packing or Taping Type ; Ex.TO-92: TZ, SOT-89: T1, SOT-23-5, SC-82AB: TR are prescribed as standard directions. (Refer to Taping Specifications.) Antistatic bag for samples: C

PIN CONFIGURATION

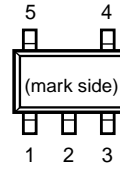
● TO-92



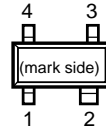
● SOT-89



● SOT-23-5



● SC-82AB



PIN DESCRIPTION

● TO-92

Pin No.	Symbol
1	V _{DD}
2	GND
3	OUT

● SOT-89

Pin No.	Symbol
1	OUT
2	V _{DD}
3	GND

● SOT-23-5

Pin No.	Symbol
1	OUT
2	V _{DD}
3	GND
4	NC
5	NC

● SC-2AB

Pin No.	Symbol
1	OUT
2	V _{DD}
3	NC
4	GND

ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
V _{DD}	Supply Voltage	12	V
V _{OUT1}	Output Voltage (CMOS)	V _{SS} -0.3 to V _{DD} +0.3	V
V _{OUT2}	Output Voltage (Nch)	V _{SS} -0.3 to 12	V
I _{OUT}	Output Current	70	mA
P _D	Power Dissipation 1* ^{Note1}	300	mW
P _D	Power Dissipation 2* ^{Note2}	150	mW
T _{opt}	Operating Temperature Range	-40 to 85	°C
T _{stg}	Storage Temperature Range	-55 to 125	°C
T _{solder}	Lead temperature (Soldering)	260°C, 10s	

*Note 1: applied to SOT-89 and TO-92

*Note 2: applied to SOT-23-5 and SC-82AB

ELECTRICAL CHARACTERISTICS

R3111x091A/C

Topt=25°C

Symbol	Item	Conditions	MIN.	TYP.	MAX.	Unit
-V _{DET}	Detector Threshold		0.882	0.900	0.918	V
V _{HYS}	Detector Threshold Hysteresis		0.027	0.045	0.063	V
I _{SS}	Supply Current	V _{DD} =0.80V 2.90V		0.8 0.9	2.4 2.7	μA
V _{DDH}	Maximum Operating Voltage				10	V
V _{DDL}	Minimum Operating Voltage* ^{Note1}	Topt=25°C		0.55	0.70	V
		-40°C≤Topt≤85°C		0.65	0.80	
I _{OUT}	Output Current (Driver Output Pin)	Nch V _{DS} =0.05V, V _{DD} =0.70V	0.01	0.05		mA
		V _{DS} =0.50V, V _{DD} =0.85V	0.05	0.50		
		Pch V _{DS} =-2.1V, V _{DD} =4.5V	1.0	2.0		mA
t _{PLH}	Output Delay Time* ^{Note2}				100	μs
Δ-V _{DET} /ΔT	Detector Threshold Temperature Coefficient	-40°C≤Topt≤85°C		±100		ppm/°C

R3111x181A/C

Topt=25°C

Symbol	Item	Conditions	MIN.	TYP.	MAX.	Unit
-V _{DET}	Detector Threshold		1.764	1.800	1.836	V
V _{HYS}	Detector Threshold Hysteresis		0.054	0.090	0.126	V
I _{SS}	Supply Current	V _{DD} =1.70V 3.80V		0.8 1.0	2.4 3.0	μA
V _{DDH}	Maximum Operating Voltage				10	V
V _{DDL}	Minimum Operating Voltage* ^{Note1}	Topt=25°C		0.55	0.70	V
		-40°C≤Topt≤85°C		0.65	0.80	
I _{OUT}	Output Current (Driver Output Pin)	Nch V _{DS} =0.05V, V _{DD} =0.70V	0.01	0.05		mA
		V _{DS} =0.50V, V _{DD} =0.85V	1.00	2.00		
		Pch V _{DS} =-2.1V, V _{DD} =4.5V	1.0	2.0		mA
t _{PLH}	Output Delay Time* ^{Note2}				100	μs
Δ-V _{DET} /ΔT	Detector Threshold Temperature Coefficient	-40°C≤Topt≤85°C		±100		ppm/°C

● R3111x271A/C

Topt=25°C

Symbol	Item	Conditions	MIN.	TYP.	MAX.	Unit
-V _{DET}	Detector Threshold		2.646	2.700	2.754	V
V _{HYS}	Detector Threshold Hysteresis		0.081	0.135	0.189	V
I _{SS}	Supply Current	V _{DD} =2.60V 4.70V		0.9 1.1	2.7 3.3	μA
V _{DDH}	Maximum Operating Voltage				10	V
V _{DDL}	Minimum Operating Voltage* ^{Note1}	Topt=25°C		0.55	0.70	V
		-40°C≤Topt≤85°C		0.65	0.80	
I _{OUT}	Output Current (Driver Output Pin)	Nch V _{DS} =0.05V, V _{DD} =0.70V V _{DS} =0.50V, V _{DD} =1.50V	0.01 1.00	0.05 2.00		mA
		Pch V _{DS} =-2.1V, V _{DD} =4.5V	1.0	2.0		mA
t _{PLH}	Output Delay Time* ^{Note2}				100	μs
Δ-V _{DET} /ΔT	Detector Threshold Temperature Coefficient	-40°C≤Topt≤85°C		±100		ppm/°C

● R3111x361A/C

Topt=25°C

Symbol	Item	Conditions	MIN.	TYP.	MAX.	Unit
-V _{DET}	Detector Threshold		3.528	3.600	3.672	V
V _{HYS}	Detector Threshold Hysteresis		0.108	0.180	0.252	V
I _{SS}	Supply Current	V _{DD} =3.47V 5.60V		1.0 1.2	3.0 3.6	μA
V _{DDH}	Maximum Operating Voltage				10	V
V _{DDL}	Minimum Operating Voltage* ^{Note1}	Topt=25°C		0.55	0.70	V
		-40°C≤Topt≤85°C		0.65	0.80	
I _{OUT}	Output Current (Driver Output Pin)	Nch V _{DS} =0.05V, V _{DD} =0.70V V _{DS} =0.50V, V _{DD} =1.50V	0.01 1.00	0.05 2.00		mA
		Pch V _{DS} =-2.1V, V _{DD} =4.5V	1.0	2.0		mA
t _{PLH}	Output Delay Time* ^{Note2}				100	μs
Δ-V _{DET} /ΔT	Detector Threshold Temperature Coefficient	-40°C≤Topt≤85°C		±100		ppm/°C

● R3111x451A/C

Topt=25°C

Symbol	Item	Conditions	MIN.	TYP.	MAX.	Unit
-V _{DET}	Detector Threshold		4.410	4.500	4.590	V
V _{HYS}	Detector Threshold Hysteresis		0.135	0.225	0.315	V
I _{SS}	Supply Current	V _{DD} =4.34V 6.50V		1.1 1.3	3.3 3.9	μA
V _{DDH}	Maximum Operating Voltage				10	V
V _{DDL}	Minimum Operating Voltage* ^{Note1}	Topt=25°C		0.55	0.70	V
		-40°C≤Topt≤85°C		0.65	0.80	
I _{OUT}	Output Current (Driver Output Pin)	Nch V _{DS} =0.05V, V _{DD} =0.70V V _{DS} =0.50V, V _{DD} =1.50V	0.01 1.00	0.05 2.00		mA
		Pch V _{DS} =-2.1V, V _{DD} =8.0V	1.5	3.0		mA
t _{PLH}	Output Delay Time* ^{Note2}				100	μs
Δ-V _{DET} /ΔT	Detector Threshold Temperature Coefficient	-40°C≤Topt≤85°C		±100		ppm/°C

● R3111x541A/C

Topt=25°C

Symbol	Item	Conditions	MIN.	TYP.	MAX.	Unit
-V _{DET}	Detector Threshold		5.292	5.400	5.508	V
V _{HYS}	Detector Threshold Hysteresis		0.162	0.270	0.378	V
I _{SS}	Supply Current	V _{DD} =5.20V 7.40V		1.2 1.4	3.6 4.2	μA
V _{DDH}	Maximum Operating Voltage				10	V
V _{DDL}	Minimum Operating Voltage* ^{Note1}	Topt=25°C		0.55	0.70	V
		-40°C≤Topt≤85°C		0.65	0.80	
I _{OUT}	Output Current (Driver Output Pin)	Nch V _{DS} =0.05V, V _{DD} =0.70V V _{DS} =0.50V, V _{DD} =1.50V	0.01 1.00	0.05 2.00		mA
		Pch V _{DS} =-2.1V, V _{DD} =8.0V	1.5	3.0		mA
t _{PLH}	Output Delay Time* ^{Note2}				100	μs
Δ-V _{DET} /ΔT	Detector Threshold Temperature Coefficient	-40°C≤Topt≤85°C		±100		ppm/°C

*Note1: Minimum Operating Voltage means the value of input voltage when output voltage maintains 0.1V or less. (In the case of Nch Open Drain Type, Output pin is pulled up with a resistance of 470kΩ to 5.0V.)

*Note2: In the case of CMOS Output Type: The time interval between the rising edge of V_{DD} input pulse from 0.7V to (+V_{DET})+2.0V and output voltage level becoming to V_{DD}/2.

In the case of Nch Open Drain Output Type: Output pin is pulled up with a resistance of 470kΩ to 5.0V, The time interval between the rising edge of V_{DD} input pulse from 0.7V to (+V_{DET})+2.0V and output voltage level becoming to 2.5V.

ELECTRICAL CHARACTERISTICS BY DETECTOR THRESHOLD

R3111x09x to R3111x60x

Part Number	Detector Threshold			Detector Threshold Hysteresis			Supply Current 1			Supply Current 2			
	-V _{DET} [V]			V _{HYS} [V]			I _{SS1} [μA]			I _{SS2} [μA]			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	Condition	TYP.	MAX.	Condition	TYP.	MAX.	
R3111x091x	0.882	0.900	0.918	0.027	0.045	0.063	V _{DD} = (-V _{DET}) -0.10V	0.8	2.4	1.0	3.0	0.9	2.7
R3111x101x	0.980	1.000	1.020	0.030	0.050	0.070							
R3111x111x	1.078	1.100	1.122	0.033	0.055	0.077							
R3111x121x	1.176	1.200	1.224	0.036	0.060	0.084							
R3111x131x	1.274	1.300	1.326	0.039	0.065	0.091							
R3111x141x	1.372	1.400	1.428	0.042	0.070	0.098							
R3111x151x	1.470	1.500	1.530	0.045	0.075	0.105							
R3111x161x	1.568	1.600	1.632	0.048	0.080	0.112							
R3111x171x	1.666	1.700	1.734	0.051	0.085	0.119							
R3111x181x	1.764	1.800	1.836	0.054	0.090	0.126							
R3111x191x	1.862	1.900	1.938	0.057	0.095	0.133							
R3111x201x	1.960	2.000	2.040	0.060	0.100	0.140							
R3111x211x	2.058	2.100	2.142	0.063	0.105	0.147							
R3111x221x	2.156	2.200	2.244	0.066	0.110	0.154							
R3111x231x	2.254	2.300	2.346	0.069	0.115	0.161							
R3111x241x	2.352	2.400	2.448	0.072	0.120	0.168							
R3111x251x	2.450	2.500	2.550	0.075	0.125	0.175							
R3111x261x	2.548	2.600	2.652	0.078	0.130	0.182							
R3111x271x	2.646	2.700	2.754	0.081	0.135	0.189							
R3111x281x	2.744	2.800	2.856	0.084	0.140	0.196							
R3111x291x	2.842	2.900	2.958	0.087	0.145	0.203							
R3111x301x	2.940	3.000	3.060	0.090	0.150	0.210							
R3111x311x	3.038	3.100	3.162	0.093	0.155	0.217							
R3111x321x	3.136	3.200	3.264	0.096	0.160	0.224							
R3111x331x	3.234	3.300	3.366	0.099	0.165	0.231							
R3111x341x	3.332	3.400	3.468	0.102	0.170	0.238							
R3111x351x	3.430	3.500	3.570	0.105	0.175	0.245							
R3111x361x	3.528	3.600	3.672	0.108	0.180	0.252							
R3111x371x	3.626	3.700	3.774	0.111	0.185	0.259							
R3111x381x	3.724	3.800	3.876	0.114	0.190	0.266							
R3111x391x	3.822	3.900	3.978	0.117	0.195	0.273							
R3111x401x	3.920	4.000	4.080	0.120	0.200	0.280							
R3111x411x	4.018	4.100	4.182	0.123	0.205	0.287							
R3111x421x	4.116	4.200	4.284	0.126	0.210	0.294							
R3111x431x	4.214	4.300	4.386	0.129	0.215	0.301							
R3111x441x	4.312	4.400	4.488	0.132	0.220	0.308							
R3111x451x	4.410	4.500	4.590	0.135	0.225	0.315							
R3111x461x	4.508	4.600	4.692	0.138	0.230	0.322							
R3111x471x	4.606	4.700	4.794	0.141	0.235	0.329							
R3111x481x	4.704	4.800	4.896	0.144	0.240	0.336							
R3111x491x	4.802	4.900	4.998	0.147	0.245	0.343							
R3111x501x	4.900	5.000	5.100	0.150	0.250	0.350							
R3111x511x	4.998	5.100	5.202	0.153	0.255	0.357							
R3111x521x	5.096	5.200	5.304	0.156	0.260	0.364							
R3111x531x	5.194	5.300	5.406	0.159	0.265	0.371							
R3111x541x	5.292	5.400	5.508	0.162	0.270	0.378							
R3111x551x	5.390	5.500	5.610	0.165	0.275	0.385							
R3111x561x	5.488	5.600	5.712	0.168	0.280	0.392							
R3111x571x	5.586	5.700	5.814	0.171	0.285	0.399							
R3111x581x	5.684	5.800	5.916	0.174	0.290	0.406							
R3111x591x	5.782	5.900	6.018	0.177	0.295	0.413							
R3111x601x	5.880	6.000	6.120	0.180	0.300	0.420							

Note 1: In the case of CMOS Output parts; when the voltage is forced to V_{DD} from 0.7V to (+V_{DET})+2.0V, time interval between the rising edge of V_{DD} and the reaching point at 50% of Output Voltage. In the case of Nch open Drain Output parts : Output pin is pulled up to 5V through 470kΩ, and when the voltage is forced to V_{DD} from 0.7V to (+V_{DET})+2.0V, time interval between the rising edge of V_{DD} and the reaching point at 50% of Output Voltage.

Note 2: V_{DD} value when Output Voltage is equal or less than 0.1V. In the case of Nch Open Drain Output parts, Output pin is pulled up to 5V through 470kΩ resistor.

Condition 1: T_{opt}=25°C

Condition 2: -40°C ≤ T_{opt} ≤ 85°C

RICOH

Output Current 1			Output Current 2			Output Delay Time	Minimum Operating Voltage		Detector Threshold Temperature Coefficient		
I _{OUT1} [mA]			I _{OUT2} [mA]			t _{PLH} [μs]	V _{DDL} [V]		ΔV _{DET} /ΔT[ppm/°C]		
Condition	MIN.	TYP.	Condition	MIN.	TYP.	MAX.	TYP.	MAX.	Condition	TYP.	
Nch V _{DS} =0.05V V _{DD} =0.7V	0.01	0.05	Nch V _{DS} = 0.5V	V _{DD} = 0.85V	0.05	0.5	Note 1 100	Note 2	Note 2	-40°C ≤ T _{opt} ≤85°C	±100
				V _{DD} = 1.0V	0.2	1.0					
				V _{DD} = 1.5V	1.0	2.0					

OPERATION

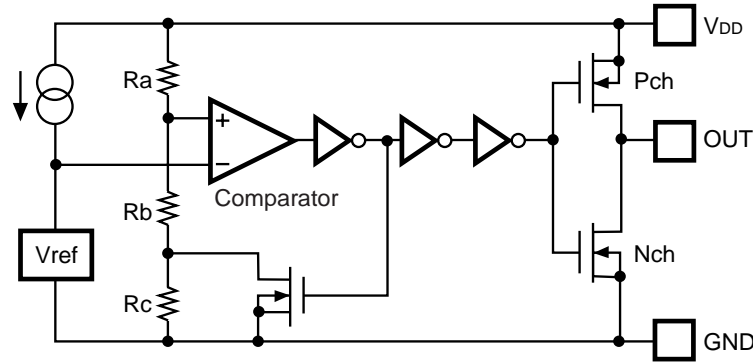


Figure 1. Block Diagram

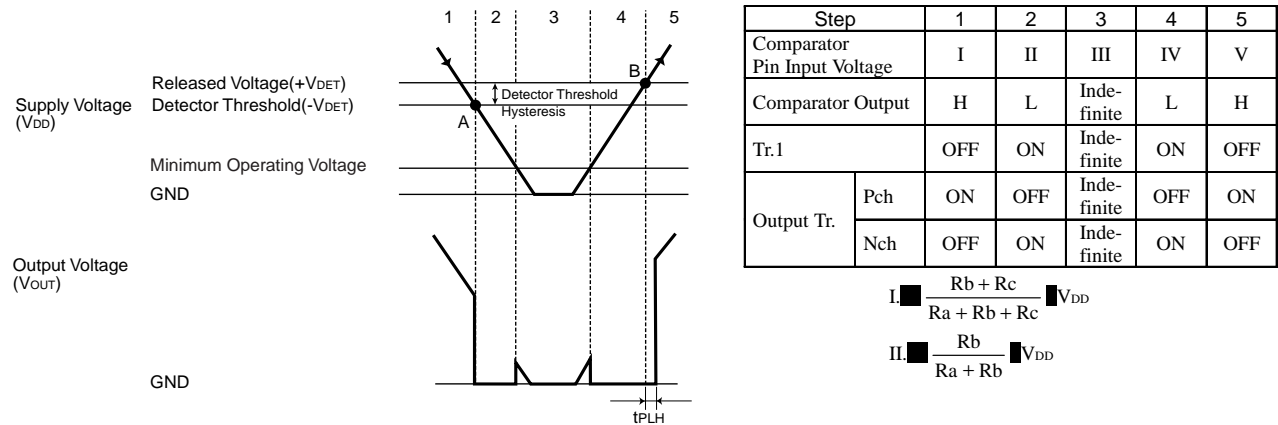


Figure 2. Operation Diagram

- Step 1. Output Voltage is equal to Supply Voltage (V_{DD}).
- Step 2. At Point "A", $V_{ref} \geq V_{DD} \times (Rb + Rc) / (Ra + Rb + Rc)$ is true, as a result, the output of comparator is reverse, and output voltage becomes to GND level. The voltage level of Point A means detector threshold voltage, or ($-V_{DET}$).
- Step 3. When the supply voltage is less than minimum operating voltage, the operation of output transistor becomes indefinite, and in the case that output is pulled up to V_{DD} , Output voltage equals to V_{DD} voltage.
- Step 4. Output Voltage equals to GND level.
- Step 5. At Point "B", $V_{ref} \leq V_{DD} \times Rb / (Ra + Rb)$ is true, Output of the comparator is reverse, and output voltage is equal to the supply voltage, or (V_{DD}). The voltage level of Point B means released voltage, or ($+V_{DET}$).
- * The difference between Released Voltage and Detector Threshold Voltage is Detector Threshold Hysteresis.

TEST CIRCUITS

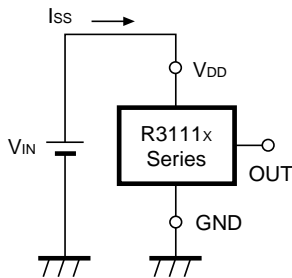
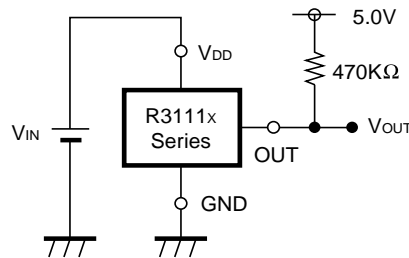


Figure 3. Supply Current Test Circuit



*Pull-up circuit is not necessary for CMOS Output type, or R3111XXXXC.

Figure 4. Detector Threshold Test Circuit

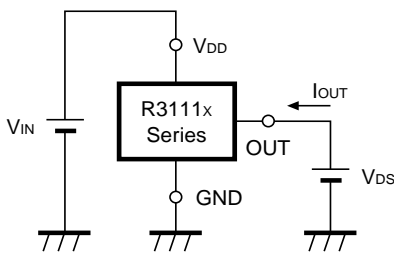
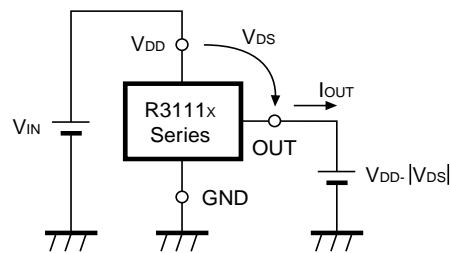


Figure 5. Nch Driver Output Current Test Circuit



*Apply only to CMOS

Figure 6. Pch Driver Output Current Test Circuit

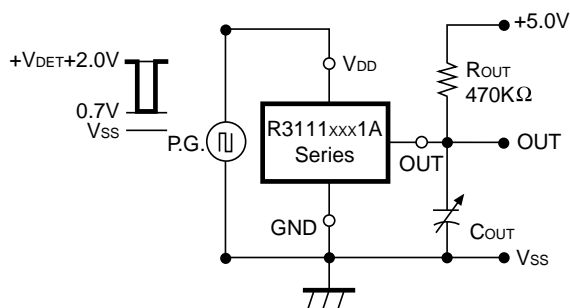


Figure 7. Output Delay Time Test Circuit (1)

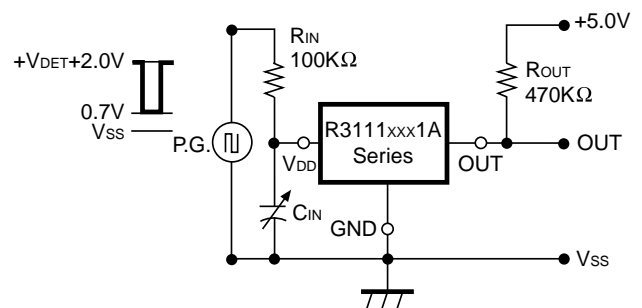
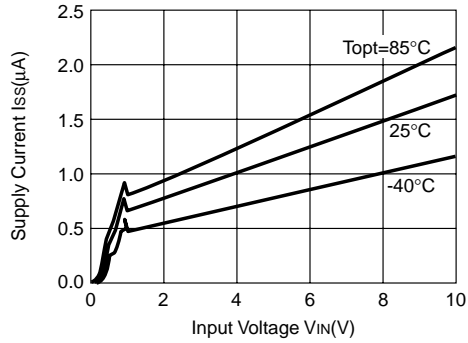


Figure 8. Output Delay Time Test Circuit (2)

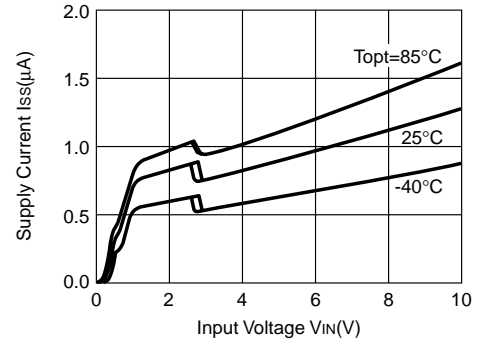
■ TYPICAL CHARACTERISTICS

1) Supply Current vs. Input Voltage

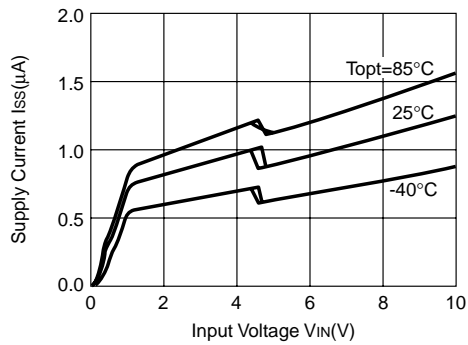
R3111x091C



R3111x271C

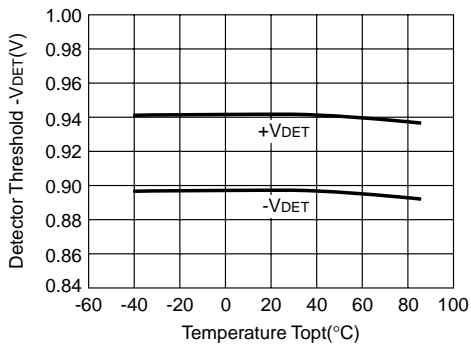


R3111x451C

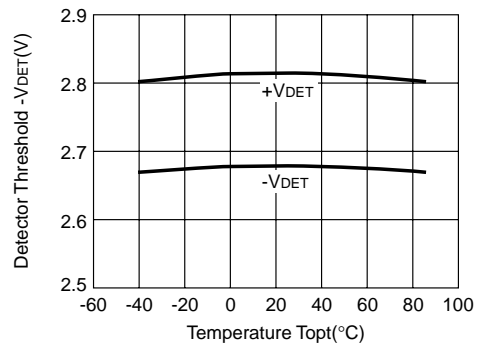


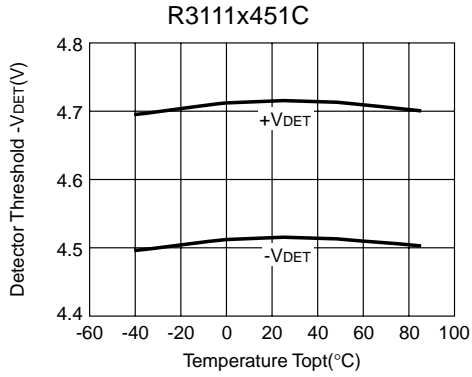
2) Detector Threshold Hysteresis vs. Temperature

R3111x091C

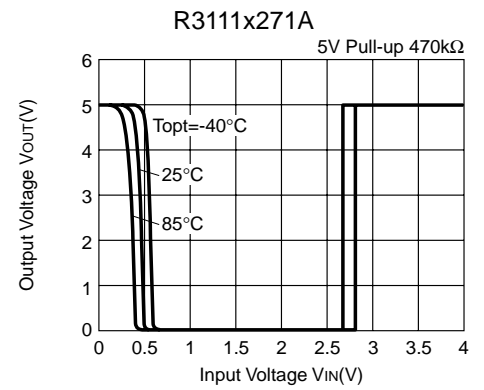
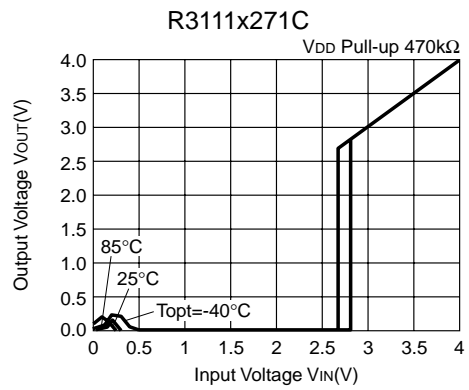
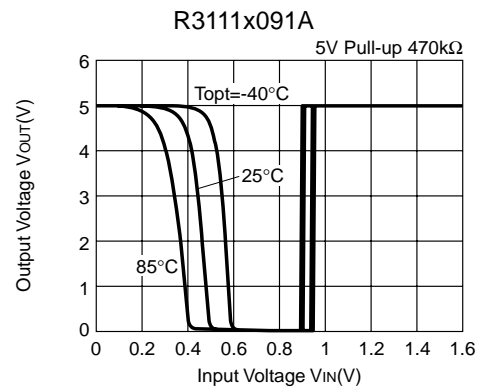
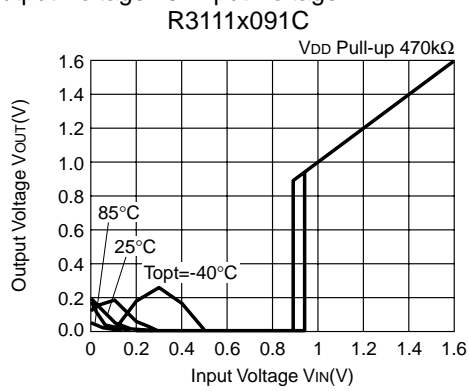


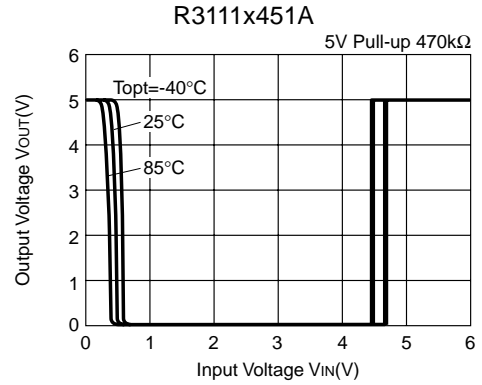
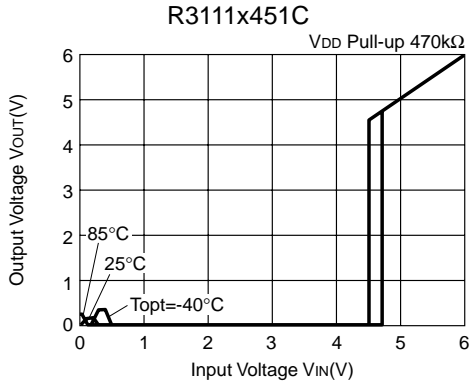
R3111x271C



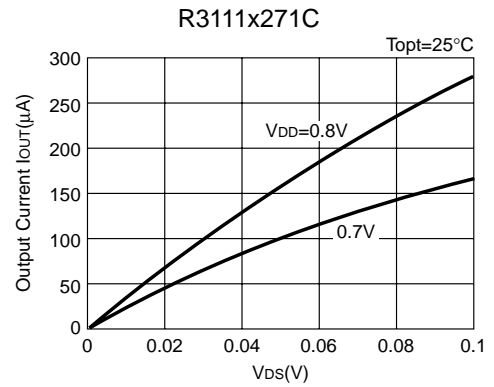
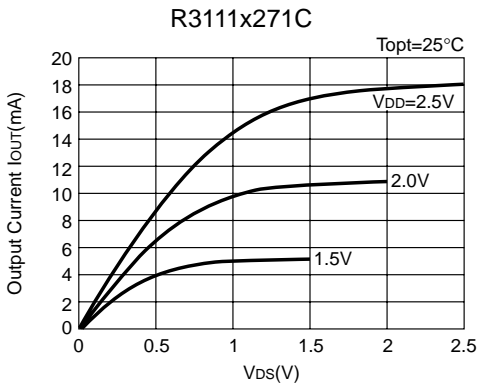
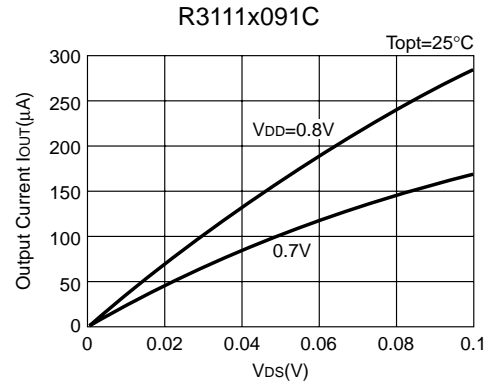
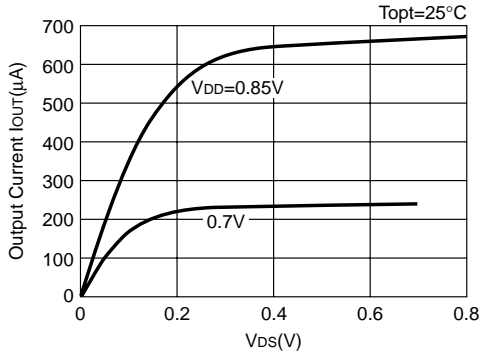


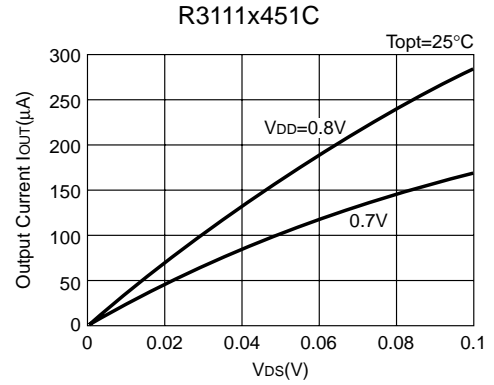
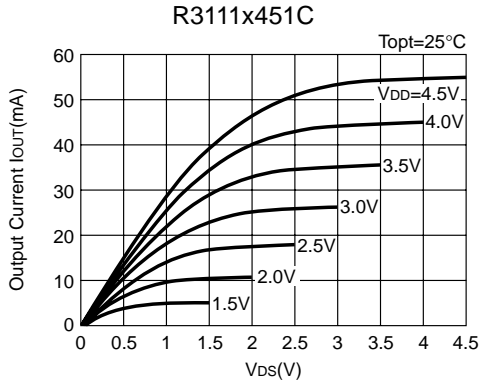
3) Output Voltage vs. Input Voltage



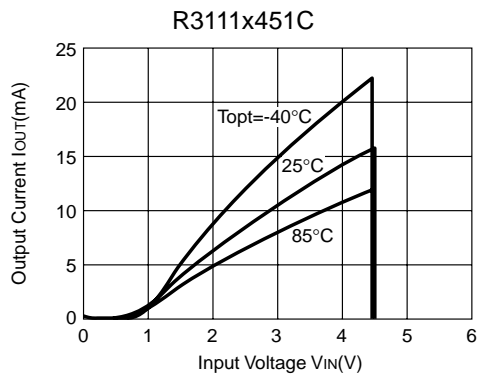
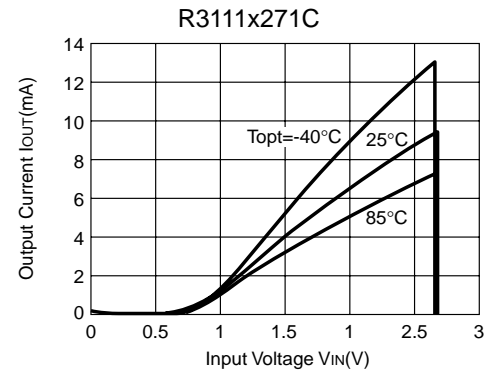
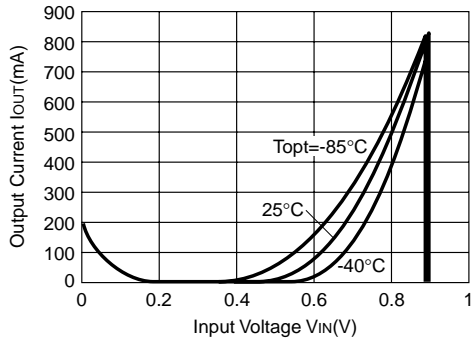


4) Nch Driver Output Current vs. V_{DS}
R3111x091C

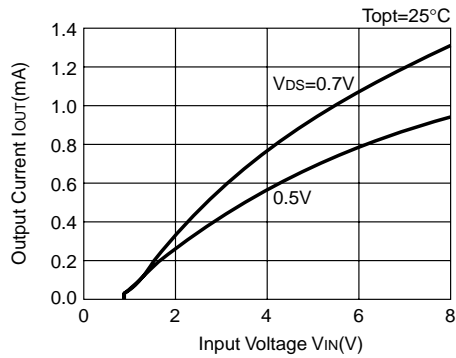




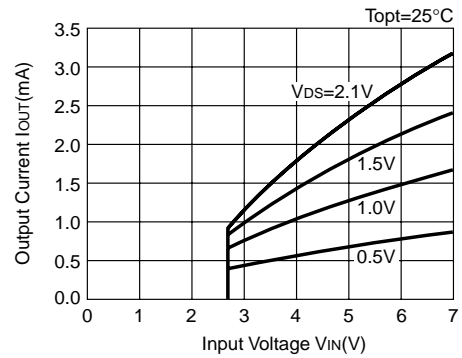
5) Nch Driver Output Current vs. Input Voltage
R3111x091C



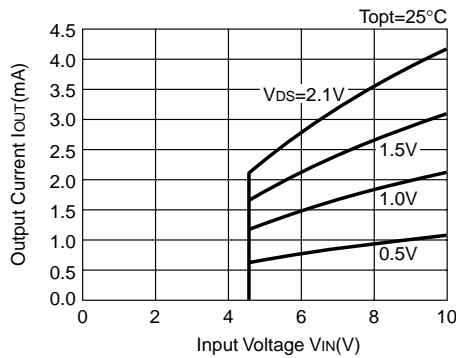
6) Pch Driver Output Current vs. Input Voltage
R3111x091C



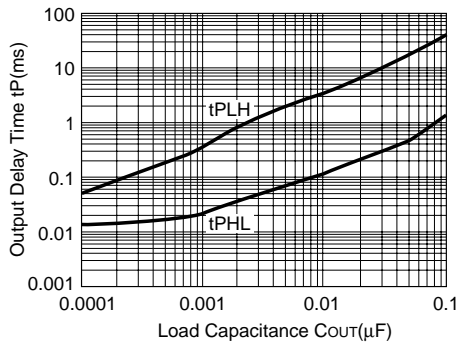
R3111x271C



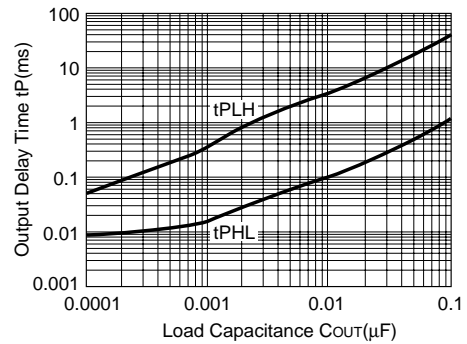
R3111x451C

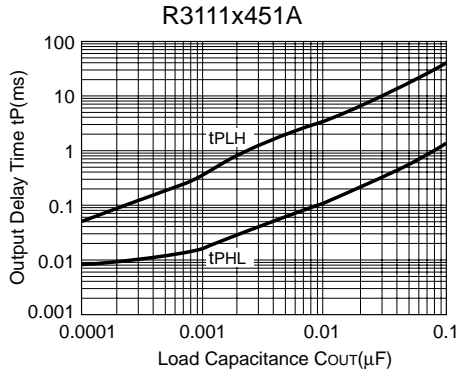


7) Output Delay Time vs. Load Capacitance
R3111x091A

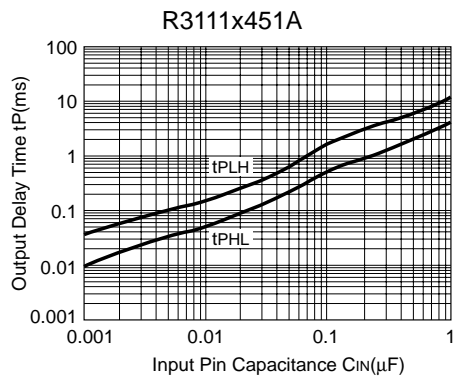
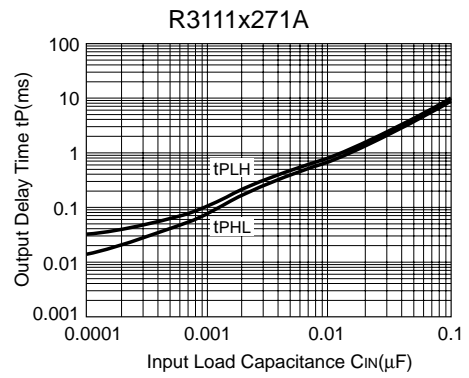
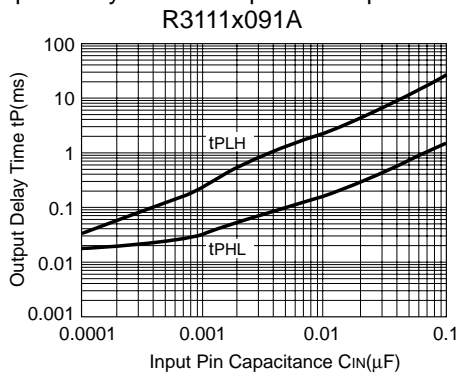


R3111x271A





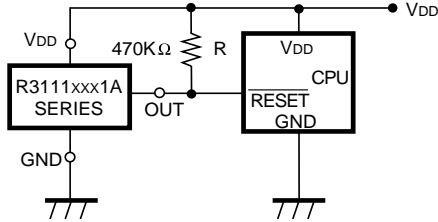
8) Output Delay Time vs. Input Pin Capacitance



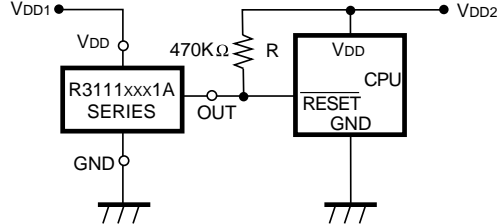
■ TYPICAL APPLICATION

● R3111xxx1A CPU Reset Circuit (Nch Open Drain Output)

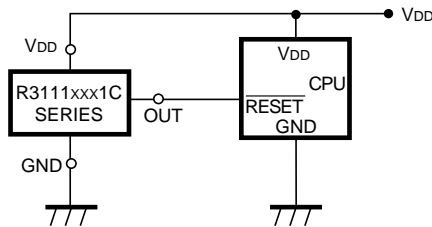
Case 1. Input Voltage to R3111xxx1A is equal to Input Voltage to CPU



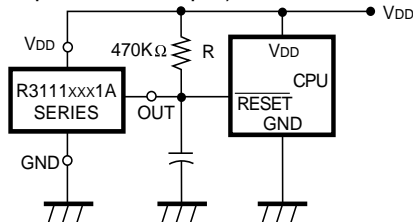
Case 2. Input Voltage to R3111xxx1A is unequal to Input Voltage to CPU



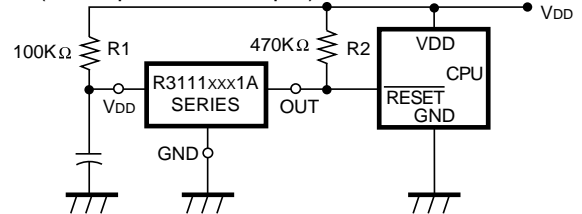
● R3111xxx1A CPU Reset Circuit CMOS Output



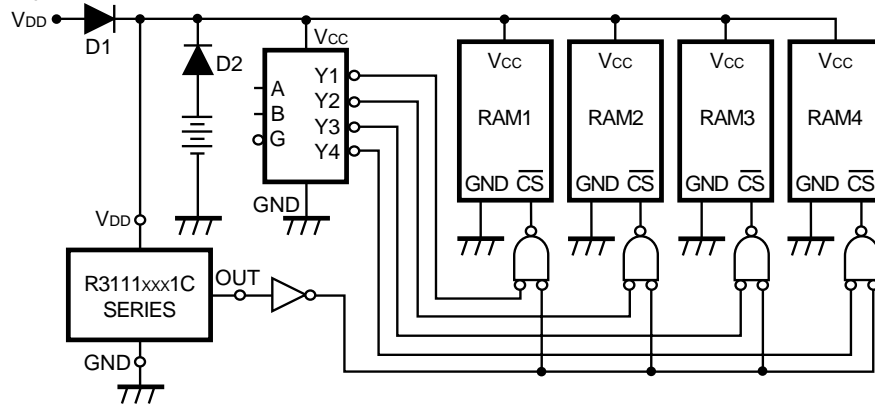
● R3111xxx1A Output Delay Time Circuit 1 (Nch Open Drain Output)



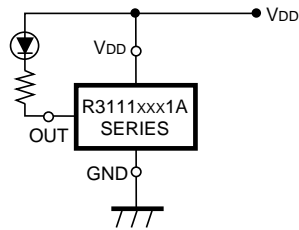
● R3111xxx1A Output Delay Time Circuit 2 (Nch Open Drain Output)



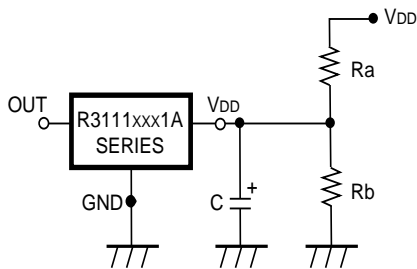
● Memory Back-up Circuit



- Voltage level Indicator Circuit (lighted when the power runs out)
(Nch Open Drain Output)



- Detector Threshold Adjustable Circuit
(Nch Open Drain Type Output)

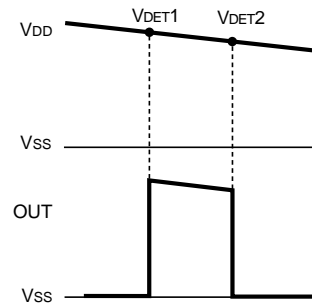
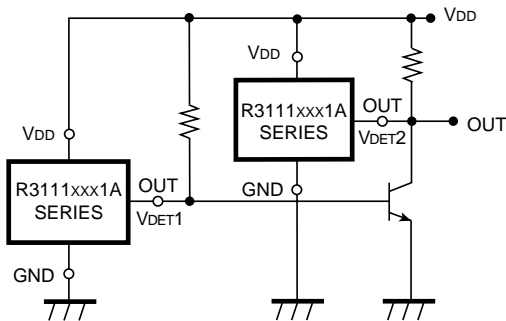


Adjusted Detector Threshold
 $= (-V_{DET}) * (Ra + Rb) / Rb$

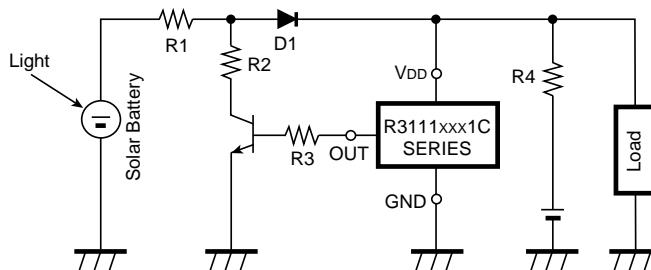
Hysteresis Voltage
 $= (V_{HYS}) * (Ra + Rb) / Rb$

*) If the value of Ra is set excessively large, voltage drop may occur caused by the supply current of IC itself, and detector threshold may vary.

- Window Comparator Circuit
(Nch Open Drain Output)



- Over-charge Preventing Circuit



TECHNICAL NOTES

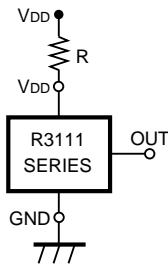


Figure 9

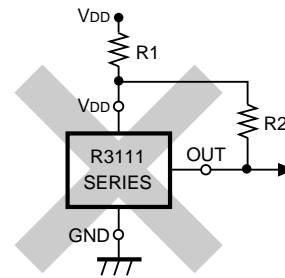


Figure 10

1. In Figure 9, When R3111xxx1C is used, and if an impedance is connected in between Voltage Supplier and the V_{DD} Pin of R3111xxx1C Series, the operation might be unstable by through-type current at detection. When R3111xxx1A is used in Figure 9, if the value of R is set excessively large, voltage drop may occur caused by supply current of IC itself and Detector threshold may vary.
2. Wiring as shown in Figure 10 may cause the oscillation in both output types of R3111 Series.